

SB160M-40

Silicon Epitaxial Planer Schottky Barrier Diode

Features

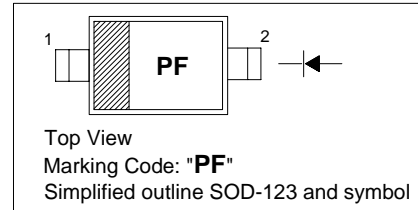
- High reliability
- Low forward voltage

Application

- For switching power supplies
- Battery protection against reversal current

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode

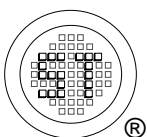


Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Reverse Voltage (Repetitive Peak)	V_{RM}	40	V
Reverse Voltage (DC)	V_R	40	V
Average Rectified Forward Current	I_O	1	A
Peak Forward Surge Current (60Hz / cyc.)	I_{FSM}	30	A
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-40 to 150	$^\circ\text{C}$

Electrical Characteristics ($T_a = 25\text{ }^\circ\text{C}$)

Parameter	Symbol	Min.	Max.	Unit
Forward Voltage at $I_F = 1\text{ A}$	V_F	-	0.51	V
Reverse Current at $V_R = 40\text{ V}$	I_R	-	30	μA



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Dated : 22/04/2006

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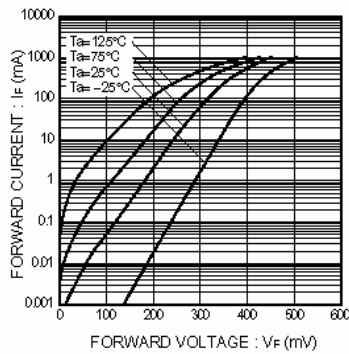


Fig. 1 Forward Temperature Characteristics

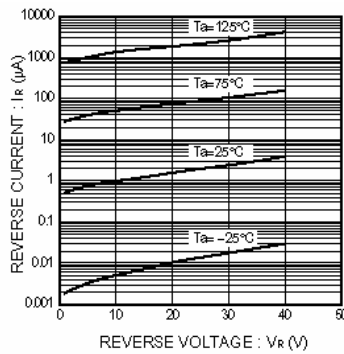


Fig. 2 Reverse Temperature Characteristics

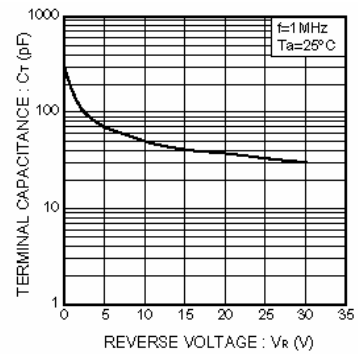


Fig. 3 Capacitance Between Terminals Characteristics

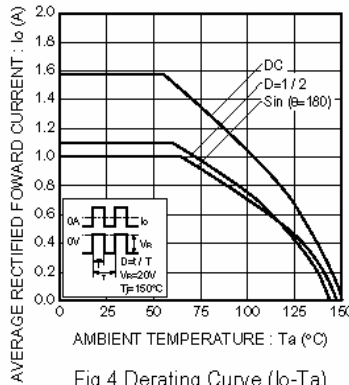


Fig. 4 Derating Curve (Io-Ta)

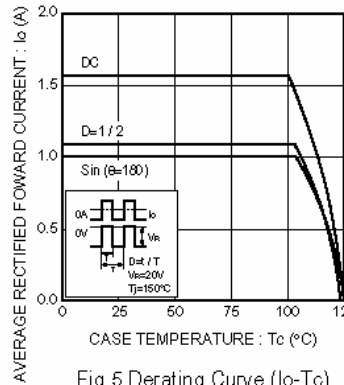


Fig. 5 Derating Curve (Io-Tc)

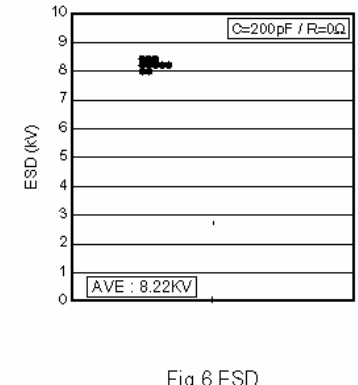
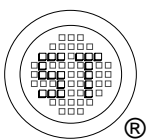


Fig. 6 ESD



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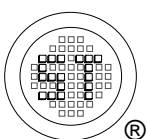
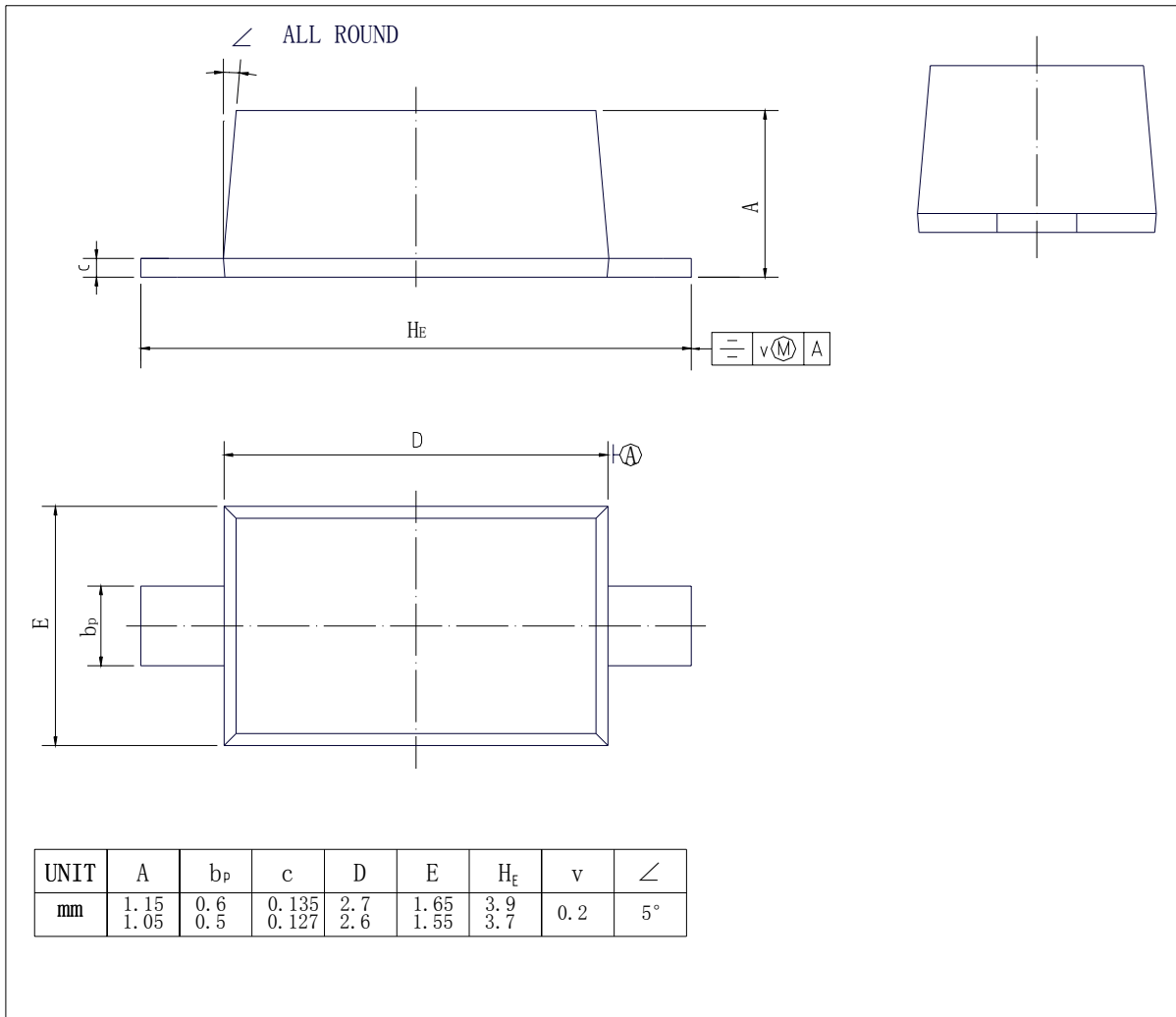
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PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-123



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